

HOW RF TRANSFORMERS WORK

AND HOW THEY ARE MEASURED

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APPLICATIONS FOR RF TRANSFORMERS

RF transformers are widely used in electronic circuits for

- Impedance matching to achieve maximum power transfer and to suppress undesired signal reflection.
- Voltage, current step-up or step-down.
- DC isolation between circuits while affording efficient AC transmission.
- Interfacing between balanced and unbalanced circuits; example: balanced amplifiers.

TRANSFORMER CIRCUITS AND IMPEDANCE RELATIONSHIPS

When signal current goes through the primary winding, it generates a magnetic field which induces a voltage across the secondary winding. Connecting a load to the secondary causes an AC current to flow in the load.

It is generally necessary to control terminating impedances of RF signal paths, especially in wideband applications where path lengths are not negligible relative to wavelength. Wideband RF transformers are wound using twisted wires which behave as transmission lines, and the required coupling occurs along the length of these lines as well as magnetically via the core. Optimum performance is achieved when primary and secondary windings are connected to resistive terminating impedances for which the transformer is designed. Transformers having a turns ratio of 1:1, for example, are typically designed for use in a 50- or 75-ohm system.

In this application note, reference is continually made to terminating impedances which the user should provide for transformers, both for performance testing and in actual use. For the sake of consistency in the discussion, transformers with turns ratio greater than 1:1 will be described as step-up; that is, the secondary impedance is greater than the primary impedance. In actual use, however, connection can be step-up or step-down as needed.

In Figure 1, three transformer winding topologies are illustrated. The one in

Figure 1a is the simplest. Called an autotransformer, this design has a tapped continuous winding and no DC isolation. The transformer in Figure 1b has separate primary and secondary windings, and provides DC isolation. The RF performance of these configurations is similar, however. The relationship of voltage and current between primary and secondary windings, as well as the terminating impedances, are given by the following equations.

 $V_2 = N V_1$ and $I_2 = I_1 \div N$, where N is the turns ratio.

Since $Z_2 = V_2 \div I_2$ and $Z_1 = V_1 \div I_1$, $Z_2 = N^2 Z_1$. That is, the impedance ratio is the square of the turns ratio.



The secondary winding in Figure 1c has a center-tap, which makes the transformer useful as a balanced signal splitter; excellent amplitude and phase balance are obtainable with well designed RF transformers having this configuration.



Figure 1c Transformer with Center-tapped Secondary

In the equations for Figure 1c which follow, the turns ratio N refers to the entire secondary winding.

$$V_4 = N V_1$$
, and $V_2 = V_3 = N V_1 \div 2$

When the two halves of the secondary are connected to equal terminating impedances Z_2 and Z_3 , then

$$I_2 = I_3 = I_1 \div N$$
; $Z_4 = N^2 Z_1$, and $Z_2 = Z_3 = Z_4 \div 2 = N^2 Z_1 \div 2$

A variation on the transformer of Figure 1c, favoring high frequency performance, is shown in Figure 2. It adds a transmission-line transformer in cascade at the input, to convert an unbalanced signal to balanced at the input to the center-tapped transformer. Features of this design:

- Wide bandwidth, exceeding 1000 MHz.
- Excellent amplitude and phase balance.
- Higher return loss (lower VSWR) at the primary side.



TRANSFORMER PERFORMANCE CHARACTERISTICS

Insertion Loss and Frequency Bandwidth

Insertion loss of a transformer is the fraction of input power lost when the transformer is inserted into an impedance-matched transmission system in place of an ideal (theoretically lossless) transformer having the same turns ratio. Actual insertion loss is affected by non-ideal characteristic impedance of the transformer windings, as well as winding and core losses.

Typical insertion loss variation with frequency is illustrated in Figure 3 which shows the 1 dB, 2 dB, and 3 dB bandwidths, referenced to the midband loss as they are usually specified. Insertion loss at low frequency is affected by the parallel (magnetizing) inductance. At low temperature, low-frequency insertion loss tends to increase because of decreasing permeability of the magnetic core. High-frequency insertion loss is attributed to interwinding capacitance, series (leakage) inductance, and core and conductor losses. At high temperature it tends to become greater due to increase in the loss component of core permeability.



Figure 3 Typical Frequency Response of an RF Transformer

A further influence on transformer insertion loss is high AC or DC current. Most RF transformers are used in small-signal applications, in which typically up to 250 mW of RF or 30 mA of unbalanced DC current pass through the windings. In the interest of small size and widest bandwidth, the smallest practical size of cores is used. When insertion loss specifications must be met with greater RF power or DC current applied, this must be taken into account in the transformer design to prevent saturation of the magnetic core and consequent bandwidth reduction.

How is insertion loss of a transformer measured? This question is especially pertinent for impedance ratios other than 1:1 because accommodation must be made for the impedance of test instrumentation, which is generally a constant 50 or 75 ohms. There are three methods:

- Three transformers are tested in pairs: A and B, A and C, B and C. Each pair is measured back-to-back; that is, the high-impedance windings are directly connected to one another, and the low-impedance windings face the source and detector of the instrumentation which match the transformer impedance. This results in 3 values of combined insertion loss, so that the values of the 3 unknowns (the individual A, B, C insertion losses) can be calculated.
- A transformer is measured individually with a minimum-loss pad as a matching circuit connected between the high-impedance winding and the instrumentation. This has been found practical for testing 50-ohm to 75-ohm transformers, for which matching pads are readily available. The loss of the matching circuit (in dB) has to be subtracted from the measured value to yield the insertion loss of the transformer itself. This method is applicable where only 2 connections are made to the secondary.

Figure 4 shows the performance of a 50- to 75-ohm transformer, model TC1.5-1, tested by this method. The loss of the matching pad was determined by measuring two of them back-to-back, and dividing the dB-value by 2.



If the transformer has a center-tapped secondary winding, then it can be connected as a 180° power splitter. Each half of the secondary must be terminated by a matching impedance $N^2 Z_1 \div 2$, referring to the equations given for Figure 1c. This requires a matching network to be used between the transformer and the sensing test-port of the insertion loss instrumentation. Because an individual test port sees only one output, both 3 dB for the split and the loss of the matching network must be subtracted from the measured value of insertion loss. By sensing both outputs, amplitude and phase unbalance can also be measured by this method. Element values and loss of the matching network are listed in Table 1.

Note: because instrumentation requiring proper source termination is connected to one or both outputs in this method, special design considerations apply to the matching network, and it should not be a minimum-loss pad. This is discussed in detail in the section entitled Measurement of Amplitude and Phase Balance of Center-tapped Transformers, where design criteria, element values, and insertion loss for suitable matching networks are given.

To demonstrate the usefulness of this method for center-tapped transformers having a wide range of impedance ratios (N^2 values), insertion loss vs. frequency is shown in Figures 5, 6, and 7 for the following models:

Figure No.	Model	Impedance ratio, 1:N ²	
5	ADTT1-1	1:1	
6	ADT4-1WT	1:4	
7	ADT16-1T	1:16	

Actual midband insertion loss is noted above each graph.

Figure 5 Model ADTT1-1 Insertion Loss











Impedance and Return Loss

Impedance looking into the secondary winding is measured with the primary winding terminated in its specified impedance (usually 50 or 75 ohms), and compared with the theoretical terminating value (Z_2 , Z_3 , or Z_4 in Figure 1).

Return loss, or VSWR, is measured at the primary winding, with the secondary terminated in its theoretical impedance; e.g., $2 \times Z_{primary}$ for a 1:2 impedance-ratio (1:1.414 turns-ratio) transformer.

PHYSICAL PARAMETERS OF A TRANSFORMER

The performance of RF transformers can be understood with the help of the equivalent circuit in Figure 8.



Figure 8 - Equivalent Circuit of Transformer

 L_1 and L_2 are the primary and secondary leakage inductances, caused by incomplete magnetic coupling between the two windings. Because their reactance is proportional to frequency, these inductances increase insertion loss and reduce return loss at high frequency.

 R_1 and R_2 are the resistance, or copper loss, of the primary and secondary windings. Skin effect increases the resistance at high frequencies, contributing to the increase in insertion loss.

Intra-winding capacitances C_1 and C_2 , as well as interwinding capacitance C, also contribute to performance limitations at high frequency. However, the distinct advantage of the transmission line design used in RF transformers is that much of the interwinding capacitance is absorbed into the transmission line parameters together with the leakage inductance (parallel capacitance and series inductance), resulting in much wider bandwidth than is obtainable with conventional transformer windings.

 L_p is the magnetizing inductance, which limits the low frequency performance of the transformer. It is determined by the permeability and crossectional area of the magnetic core, and by the number of turns. Insertion loss increases and return loss decreases at low frequency. Further, permeability of many core materials decreases with a decrease in temperature, and increases above room temperature. This accounts for the spread of the lower frequency portion of the insertion loss curves in Figure 3 as explained above.

Temperature variation of the capacitances and the leakage inductances is relatively small. The winding resistances do vary, increasing with temperature, and contribute to the spread of the high frequency portion of the curves in Figure 3.

The resistance R_c represents core loss. There are generally three contributions to this loss:

- eddy-current loss, which increases with frequency
- hysteresis loss, which increases with flux density (applied signal level)

• residual loss, due partially to gyromagnetic resonance

We can picture the applied RF signal as causing vibratory motion of the magnetic domains of the core material, which behave as particles having inertia and friction. The motion therefore causes a loss of energy. Higher frequency signals cause faster motion, thus greater core loss, and this is represented by a decrease in the value of R_c . At high temperature, random thermal vibration is greater and adds to the energy which the RF signal must expend to control the movement of the magnetic domains. Thus, core loss contributes to the increase in insertion loss and decrease in return loss at high frequency. These effects are accentuated at high temperature as shown in Figure 3.

MEASUREMENT OF AMPLITUDE AND PHASE BALANCE: CENTER-TAPPED TRANSFORMERS

Definitions

Amplitude balance, sometimes called "unbalance", is the absolute value of the difference in signal amplitude, in dB, between the two outputs of a center-tapped transformer using the center tap as a ground reference.

Phase balance, sometimes called "unbalance", is the absolute value of the difference in signal phase between the two outputs of a center-tapped transformer using the center tap as a ground reference, after subtracting the 180-degree nominal value of the phase-split.

Measurement Method: Matching Network Between Each Half of the Transformer Secondary and Sensing Port in the Test Instrumentation

It was mentioned above, toward the end of the section on insertion loss measurement, that a transformer having a center-tapped secondary can be tested like a power splitter. There is a difference which must be considered, however: A device built as a power splitter has an internal circuit which provides isolation between the outputs; that provision ensures constant impedance looking into each output port independent of the load on the other output. A transformer on the other hand, being a simpler device, lacks isolation. Thus, the design of the matching network must take into account not only the primary source impedance transformed by the primary-to-half-secondary ratio, but another impedance in parallel with it: the input impedance of whatever is terminating the other half-secondary winding.

The situation is illustrated in Figure 9. R_t is the source and sensing port impedance of the test instrumentation, as well as the impedance for which the primary of the transformer is designed. The total secondary must be terminated in $N^2 R_t$. Therefore, each of the matching networks, while its output is terminated in R_t , must have an input impedance $N^2 R_t \div 2$.

The output source impedance of each matching network, because it has to feed a cable presenting a load R_t , must also equal R_t . This must be while the matching network is being fed from a source impedance which is the parallel combination of two impedances as follows: One is the transformed source impedance R_t which appears at the half-secondary as $(N \div 2)^2 R_t$. The other is the input of the other matching network, $N^2 R_t \div 2$, coupled from one half-secondary to the other. The resultant is $N^2 R_t \div 6$.



Figure 9 Impedance Relationships for Center-tapped Transformer with Matching Networks

The impedance constraints for the matching network require three topologies depending upon the value of the transformer impedance ratio N^2 , as shown in Figures 10a through 10c.



Figure 10 Impedance Matching Constraints

For each of the two non-trivial cases, 10a and 10c, the requirements for input and output

impedance to the network provide two equations to solve for the two unknowns R_s and R_p . For $N^2 < 3$, referring to Figure 10a, the equations are:

$$\left(R_{t}+R_{s}\right) \parallel R_{p}=\frac{N^{2}}{2}R_{t}$$
 and $\left(\frac{N^{2}}{6}R_{t}\right) \parallel R_{p}+R_{s}=R_{t}$

The solution is:

For $N^2 > 3$, referring to Figure 10c, the equations are:

$$R_p \parallel R_t + R_s = \frac{N^2}{2} R_t \qquad \text{and} \qquad$$

The solution is:

For $N^2 = 3$, $R_s = R_t \div 2$ and R_p is infinite.

For accurate RF phase balance measurement, the construction of the matching networks and the connections to them should be such as to provide electrical symmetry between the two halves of the circuit.

To show the effectiveness of the above method, it was used to test transformers for amplitude and phase unbalance, with results shown in Figures 11, 12, and 13. These are the same transformers for which insertion loss was given in Figures 5, 6, and 7.

 $\left(\frac{N^2}{6} R_t + R_s\right) \parallel R_p = R_t$



Figure 13 Model ADT16-1 Amplitude, Phase Unbalance





Figure 14 - Voltage Relationships for Transformer with Matched Secondary Terminations

The remaining task is to derive expressions for the insertion loss of the matching network, so that it can be subtracted from measured values to yield insertion loss for the center-tapped transformer itself when it is tested by the "power splitter" method described above. As a reminder, 3 dB (for the split) must also be subtracted from the measured values.

Figure 14 shows voltage relationships for a transformer with the secondary terminated in matched resistive impedances.

The voltage across the primary is half the open-circuit source voltage V_i , because the impedance looking into the primary is R_t . The power delivered to each terminating resistor is the square of the voltage divided by the resistance:

$$P_O = \left(\frac{NV_i}{4}\right)^2 / \frac{N^2}{2}R_t = \frac{V_i^2}{8R_t}$$

Figure 15 shows what happens when the various matching networks are inserted after the half-secondary, and the matched load per Figure 10 is replaced by R_t which represents the sensor port in the instrumentation.



Figure 15 Voltage Relationships for Power Calculation

Figure 15a includes the "N² < 3" matching network of Figure 10a. The power delivered to the load R_t is P_{OL} (the subscript L designates the low N² case):

$$P_{OL} = \left(\frac{R_t}{R_t + R_s}\right)^2 \frac{N^2 V_i^2}{16 R_t} = \frac{R_t N^2 V_i^2}{16 (R_t + R_s)^2} \qquad Loss = P_O / P_{OL} = 2 \frac{(R_t + R_s)^2}{N^2 R_t^2}$$

Figure 15b illustrates the $N^2 = 3$ case per Figure 10b:

$$P_{O3} = \frac{V_i^2}{12R_i}$$
 Loss = $P_O / P_{O3} = 1.5$

Figure 15c is for $N^2 > 3$, corresponding to Figure 10c (the subscript H in P_{OH} designates the high N^2 case):

$$P_{OH} = \left(\frac{R_p R_t}{R_p R_t + R_p R_s + R_t R_s}\right)^2 \frac{N^2 V_i^2}{16R_t} \qquad Loss = P_O / P_{OH} = 2 \frac{\left(R_p R_t + R_p R_s + R_t R_s\right)^2}{N^2 R_p^2 R_t^2}$$

Table 1 lists the matching-network resistance values, normalized to R_t , as well as the network loss in dB, for values of impedance ratio for which Mini-Circuits offers center-tapped RF transformers.

Resistors available for the matching networks are typically the "1% values". Their nominal values, having increments of 2%, could thus differ from the Table 1 values of R_s and R_p by as much as \pm 1%. The resulting error in the loss of the network is greatest if R_s and R_p depart from Table 1 in opposite directions, and amounts to 0.1 dB for $N^2 = 5$, for example, in the case of 1% resistance error. If greater accuracy is needed, loss should be calculated by substituting the actual resistances in the equations following Figure 15.

The above discussion about resistor precision pertains to measurement of insertion loss of a transformer; amplitude balance is not affected by resistance error as long as the two matching networks are equal.

Z ratio, 1:N ²	R _s (Figure 10)	R _p (Figure 10)	Loss of Network, dB
1:1	0.866 R _t	0.683 R _t	8.43
1:1.5	0.791 R _t	1.291 R _t	6.31
1:2	0.707 R _t	2.414 R _t	4.64
1:2.5	0.612 R _t	5.56 R _t	3.18
1:3	0.500 R _t	None	1.76
1:4	1.333 R _t	2.000 R _t	6.53
1:5	1.887 R _t	1.581 R _t	8.23
1:8	3.44 R _t	1.265 R _t	11.08
1:13	5.97 R _t	1.140 R _t	13.60
1:16	7.47 R _t	1.109 R _t	14.61
1:25	11.98 R _t	1.066 R _t	16.71

Table 1 Matching Networks for Testing Center-tapped Transformers

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